

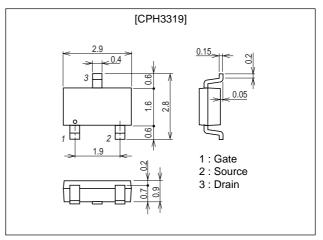
CPH3319

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.8V drive.

Package Dimensions

unit : mm 2152A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-12	V
Gate-to-Source Voltage	VGSS		±8	V
Drain Current (DC)	ID		-1.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-6	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Parameter			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-12			٧
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-12V, V _{GS} =0			-10	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±6.4V, V _{DS} =0			±10	μΑ
Cutoff Voltage	Vgs(off)	V _{DS} =-6V, I _D =-1mA	-0.3		-1.0	٧
Forward Transfer Admittance	yfs	V _{DS} =-6V, I _D =-0.8A	1.3	1.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-0.8A, V _G S=-4.5V		220	290	mΩ
	R _{DS} (on)2	I _D =-0.4A, V _G S=-2.5V		320	450	mΩ
	RDS(on)3	ID=-0.1A, VGS=-1.8V		430	650	mΩ

Marking: JU

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